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OPEN First-principles study on the structural and electronic properties of metallic HfH₂ under pressure

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The crystal structures and properties of hafnium hydride under pressure are explored using the firstprinciples calculations based on density function theory. The material undergoes pressure-induced structural phase transition $I_4/mmm \rightarrow Cmma \rightarrow P_2/m$ at 180 and 250 GPa, respectively, and all of these structures are metallic. The superconducting critical temperature T_c values of I_4/mmn , Cmma, and P2,/m are 47-193 mK, 5.99-8.16 K and 10.62-12.8 K at 1 atm, 180 and 260 GPa, respectively. Furthermore, the bonding nature of HfH, is investigated with the help of the electron localization function, the difference charge density and Bader charge analyses, which show that HfH₂ is classified as a ionic crystal with the charges transferring from Hf atom to H.

Up to now, hydrogen, the simplest and most abundant element of universe is still fascinating to physics community. The studies about hydrogen are mainly reflected in two aspects. One is the metallic and superconducting of hydrogen. The other is considered as the most promising clean energy sources with the capability of replacing fossil fuels. The former is going back to the early 1930: hydrogen was predicted to be a potential high T_c superconductor at high pressures¹⁻³, because of its low mass density and high elastic stiffness. However, hydrogen remains an insulator, despite considerable ongoing experimental effort up to pressure of 300 GPa⁴. Recently, hydrogen dense materials has been as a potential route to achieve metallization with high T_c at lower pressure. For example, high T_c with 190K in the sulfur hydrides at 200 GPa has been found by both of theoretical predicted and experimental observation⁵⁻⁷. The latter is still limited by many practical and technological factors, which requires the development of safe and efficient hydrogen storage technology.

Hydrogen can also react with transition metal elements formed metal hydrides under certain conditions and they can keep stable under ambient conditions, such as YH₂, YH₃, TiH₂, ZrH₂, HfH₂, etc⁸⁻¹¹. In addition, for transition metal, the number of d-shell electrons per atom is import for the T_o which is correlate with the important parameters of the Bardeen-Cooper-Schrieffer theory about superconductivity¹². Transition metal hydrides not only are regarded as promising potential materials for storing hydrogen¹³, but also exhibit fascinating superconducting properties. For example, the superconducting transition temperature T_c of Th₄H₁₅ is 8K at ambient conditions¹⁴. Many transition-metal dihydrides TMH_2 can form CaF₂ (*Fm*-3*m* space group) crystal structure. And in this structure, the metal atoms form a face-centered-cubic sublattice while the hydrogen atoms occupy the tetrahedral lattice sites. However, the group IVB dihydrides TiH₂, ZrH₂, and HfH₂ show a basically face-centered-tetragonal (fct) cell structure (I4/mmm space group). And these dihydrides (TiH₂, ZrH₂, and HfH₂) are applied in various fields. For instances, TiH_2 can be served as the catalyst in polymerization reaction, which is interesting in the new quenchable phases^{15,16}. ZrH₂ is widely used as a neutron moderator in nuclear reactor¹⁷⁻¹⁹. Hafnium hydride, instead of boron carbide, is a perfect neutron control materials for fast reactors²⁰.

The high-pressure development has become a vibrant area of research. Not only does pressure provide a different route to the synthesis of new compounds, but also enables many known materials to exhibit

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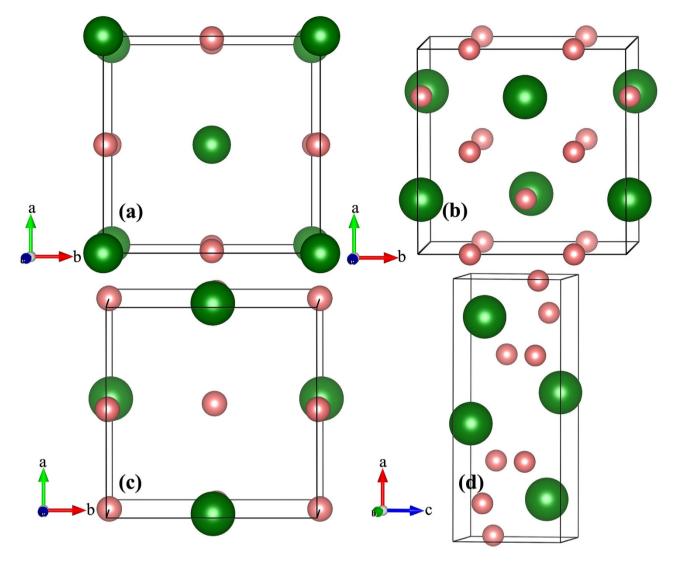


Figure 1. Crystal Structures of HfH₂. The selected stable phases for HfH₂. Green atoms depict Hf, while pink atoms present H, (a) *I*4/*mmm* at 1 atm, (b) *Cmma* at 200 GPa, (c) *P*4/*nmm* at 200 GPa and (d) $P2_1/m$ at 300 GPa.

novel phenomena that cannot be found at normal conditions. Lately, theoretical study revealed that TiH_2 at high pressure had a structural transformations $I4/mmm \rightarrow P4/nmm \rightarrow P2_1/m$ and the calculated pressure of phase transition were 63 and 294 GPa, respectively²¹. The structures and properties of ZrH_2 were also investigated in experiment under high pressure²². Despite large amounts of theoretical and experimental researches on HfH_2^{23} , there is relatively little investigation on its new structures, chemical bonding nature, dynamical properties and superconductivity under high pressures. Therefore, great attentions are needed to explore the high-pressure structures of HfH_2 .

In this paper, we examine in detail the optimum static structures of HfH_2 system at zero temperature by using the newly developed *ab initio* evolutionary algorithm. Moreover, we employ a first-principles method to calculate their dynamical stability and electronic band structures. Our calculated results show that HfH_2 adopts the *I4/mmm* structure at low pressures. On compression, *Cmma* phase possesses the lowest enthalpy, then at higher pressures $P2_1/m$ becomes energetically favorable. Band structures and density of states indicate that these structures are metallic. The estimated T_c are 47–193 mK at 1 atm, 5.99–8.16 K at 180 GPa and 10.62–12.8 K at 260 GPa, for *I4/mmm*, *Cmma* and $P2_1/m$, respectively. The electron localization function (ELF), the difference charge density and Bader charge analysis show that HfH_2 is an ionic crystal with the charge transferring from Hf to H atom. Our present study attempts to provide a better understanding of the pressure-induced phase transformations and properties of HfH_2 under pressure.

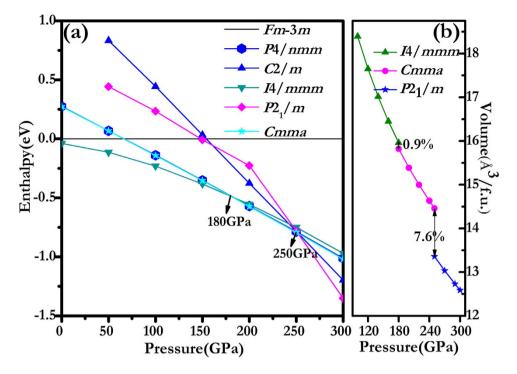


Figure 2. Enthalpy difference curves of HfH_2 and EOS. (a) Calculated enthalpies per HfH_2 unit of various structures relative to our predicted *Fm*-3*m* phase as a function of pressure range from 0 to 300 GPa. (b) Volume plotted as a function of pressure for the *I*4/*mmm*, *Cmma* and *P*2₁/*m* structures.

Results and Discussion

The crystal structure prediction were performed with simulation sizes ranging from one to four HfH₂ formula units (f.u.) at 1 atm, 50, 80, 100, 150, 200, 250 and 300 GPa. Analysis of the predicted structures gave us a shortlist of candidate structures with space groups Fm-3m, I4/mmm, P4/nmm, Cmma, P21/m and C2/m. Figure 1 shows the structural motifs of HfH₂ under high pressure. At 1 atm, we obtain two structures: a CaF₂ type structure with space group Fm-3m (4f.u./cell) and a centered tetragonal structure with space group I4/mmm (2f.u./cell) (Fig. 1(a)). At ambient conditions, many transition-metal dihydrides exist with fcc structure (i.e., a CaF₂ structure), where metal atoms form a face-centered cubic lattice, and the centers of tetrahedrons are occupied by H atoms. Note that in I4/mmm structure, Hf atoms form a body-centered tetragonal (bct) sublattice with its coordination number is 8, while the H atoms are located on the planes and present a one dimensional chain. Then we observed the most stable structure which possess simple tetragonal P4/nmm (4 f.u./cell) orthogonal Cmma (4 f.u./cell) at 200 GPa. In the above two phases, the metal atoms form a bct and fcc cell for P4/nmm and Cmma, respectively. For *Cmma*, the coordination number of Hf becomes 9. Finally, at 300 GPa, the monoclinic $P2_1/m$ phase (4 f.u. /cell) becomes the preferred one (Fig. 1(d)). And in the $P2_1/m$ structure, Hf atoms can form a little distorted bcc lattice and its coordination is 12. Within $P_{2_1/m}$ structure, Hf site is not equivalent, occupying the crystallographic 2e site, while H atoms take four different 2e sites. The lattice parameters and atomic positions of selected structures at favored pressures are summarized in Table SI. In comparison, we observed that in both HfH₂ and TiH₂²¹, the locations of metal and hydrogen atoms are similar for I4/mmm, P4/nmm and $P2_1/m$, respectively. In all above structures, the nearest H-H distances are 2.149 Å at 1 atm, much longer than that in the pure H_2 . Furthermore, with increasing pressure, H-H distances decrease and become 1.548 Å at 300 GPa, which indicate that there isn't any bonding trend among H atoms.

The phase stability of HfH_2 under pressure has been investigated systematically. Enthalpy differences as a function of pressure for these competitive solid structures together relative to Fm-3m in the pressure range from 0 to 300 GPa are plotted in Fig. 2(a). It is clearly seen that I4/mmm phase has lower enthalpies than all other candidates, which indicate it is the thermodynamic ground state. Above 180 GPa, *Cmma* (*P4/nmm*) becomes the most stable structure and remains up to 250 GPa. Then under higher pressures, a monoclinic $P2_1/m$ becomes more favored. In these two transitions, the coordination number of Hf increased from 8 to 9, 9 to 12, respectively. Surprisingly, we found that *Cmma* and *P4/nmm* are energetically nearly degenerated in the range of 0–300 GPa, and enthalpy difference is less than 1 meV/f.u.. If *I4/mmm*, *P4/nmm* and *P2_1/m* phases satisfied the stability conditions of mechanics and dynamics, the phase transition sequence of HfH₂ is similar to the TiH₂²¹. However, we found that the *P4/nmm* is not stable both in dynamical and mechanical properties (see the later discussions). The calculated equations of state (EOS) depicted in Fig. 2(b) shows that the *I4/mmm* $\rightarrow Cmma$ and *Cmma* $\rightarrow P2_1/m$ phase

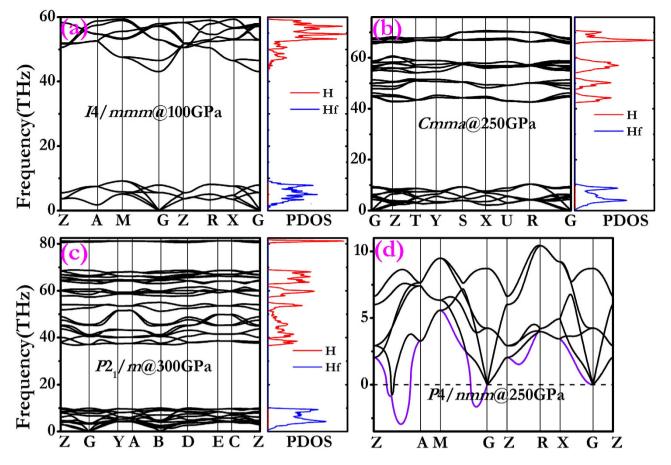


Figure 3. The phonon band structure and projected phonon DOS charts. (a–d) The phonon band structure and projected phonon DOS charts for I4/mmm, P4/nmm, Cmma and $P2_1/m$ at different pressure.

transitions are discontinuous changes in volume at the transition point with volume collapses of 0.9% and 7.6%, suggesting the two phase transitions are the first-order nature.

It is essential to determine the dynamical stability of the studied structures. The calculated phonon dispersion curves and projected phonon density of states (PHDOS) of the *I4/mmm*, *Cmma*, *P4/nmm* and $P2_1/m$ phases in the studied pressure range are presented in Fig. 3. The absence of any imaginary phonon frequencies in the entire Brillouin zone (Fig. 3(a-c)) confirms that *I4/mmm*, *Cmma* and $P2_1/m$ structures are dynamically stable regardless of the applied pressure. By contrast, there are imaginary phonon frequencies for *P4/nmm* phase (Fig. 3(d)) which indicates this phase is dynamically unstable. In addition, it is shown that two separate regions of phonon bands are clearly recognized. Since hafnium is much heavier than hydrogen atom, the vibration frequency of hafnium atom is obviously lower than that of hydrogen atom. And the low-frequency bands are merely from the Hf atoms, while higher-frequency modes are solely due to the light H atoms.

Mechanical property of the crystalline structure is one of the basic requirement when considering the phase stability. The elastic constants of I4/mmm, Cmma, $P2_1/m$ and P4/mmm structures were calculated at different pressures, as shown in Table SII. According to the mechanical stability criteria, the strain energy should be positive, which means the whole set of elastic constants matrix C_{ij} meet the Born-Huang stability criteria²⁴. Obviously, the elastic constants of I4/mmm, Cmma and $P2_1/m$ meet the mechanical stability criteria, suggesting that the three structures are mechanically stable in our studied pressure range. However, elastic constants of P4/nmm phase cannot satisfy the stability conditions of mechanics for tetragonal crystal system owing to $C_{66} < 0$, which means it is mechanically unstable.

The electronic properties were studied by calculations of the electronic band structure and partial densities of states (PDOS) for I4/mmm, Cmma and $P2_1/m$ phases at different pressures, as presented in Fig. 4. Clearly, the overlap between the conduction and the valence bands for the three structures suggests that the above phases are metallic. From the PDOS of HfH₂ (Fig. 4(d-f)), we see that the occupation properties of I4/mmm, Cmma and $P2_1/m$ phases are similar. And the pseudogap which is below the Fermi level, located at around -4.2 eV. The predominant feature of hybridization for H 1 s orbital and Hf 5d orbital is observed in the energy region below the pseudogap, while from the pseudogap to the Fermi level, the domination is Hf 5d states in the energy range. The metallic behavior of HfH₂ indicates that this material might be a superconductor and we discussed it in the following.

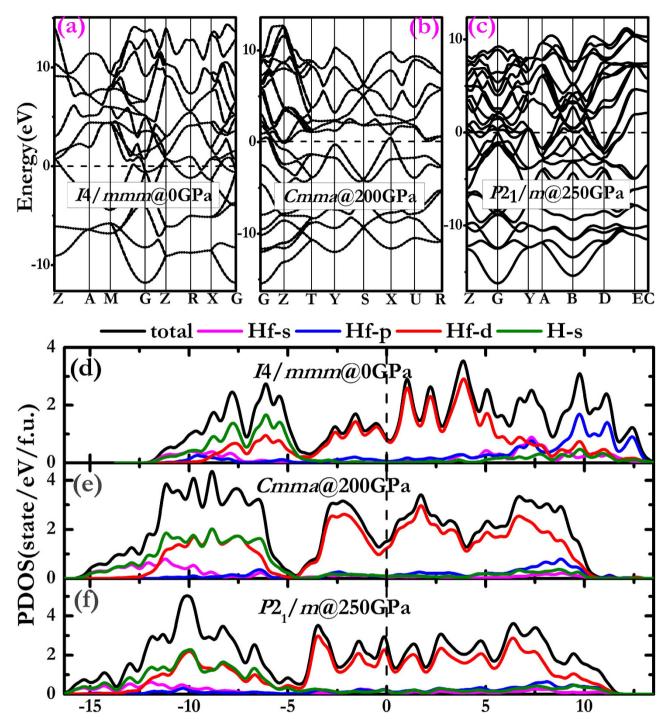


Figure 4. Electronic band structure and partial density of states (PDOS). (a–f) The calculated electronic band structure and PDOS for *I*4/*mmm* (0 GPa), *Cmma* (200 GPa) and *P*2₁/*m* (250 GPa).

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In order to explore the bonding and analyze the ionic or covalent character of HfH_2 , the electron localization function (ELF) of I4/mmm, Cmma and $P2_1/m$ at 100 GPa, 200 GPa and 250 GPa, are plotted in Fig. 5(a–c). The maximum ELF value between Hf and H is less than 0.3, which suggests no covalent bonding. In order to further clearly understand the bonding nature, we have calculated the difference charge density (crystal density minus superposition of isolated atomic densities) of I4/mmm (100 GPa), Cmma (200 GPa) and $P2_1/m$ (250 GPa), as shown in Fig. 5(d–f). We can see charges transfer from Hf atom to H atom. The profile of the Hf is identical for I4/mmm and Cmma phases in Fig. 5(d,e), respectively. By contrast, $P2_1/m$ phase in Fig. 5(f) has two Hf's contours owing to Hf sites are not equivalent, which occupy the crystallographic 2e site (Fig. 1(d)). To gain a better understanding of the bonding characters between Hf and H atoms, we calculate the q_e/atom from Hf to H by the Bader charge analysis for I4/mmm, Cmma and $P2_1/m$ at different pressures, as shown in Figure SI. We can see that about 1.22

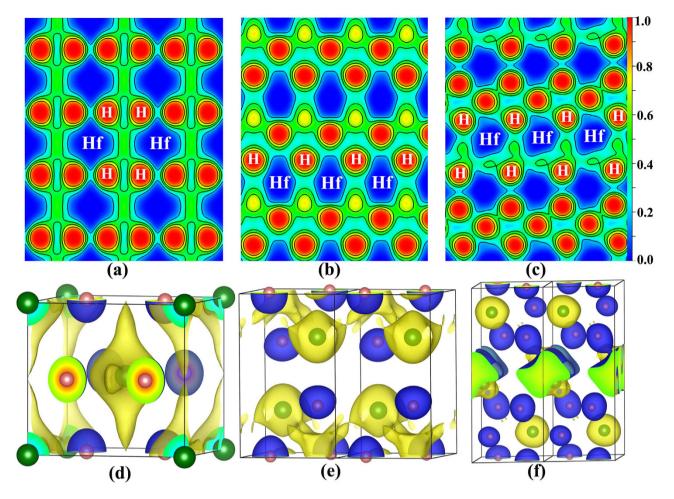


Figure 5. The electron localization function and difference charge density maps. (a–c) Electron localization function (ELF) maps of *I*4/*mmm* (100 GPa), *Cmma* (200 GPa) and *P*2₁/*m* (250 GPa), respectively. (**d**–**f**) Difference charge density (crystal density minus superposition of isolated atomic densities) of *I*4/*mmm*, *Cmma* and *P*2₁/*m* for HfH₂ plotted at 100, 200 and 250 GPa, respectively. The isosurface value is set as: Blue represent positive (+0.05) while Yellow represent negative (-0.015).

electrons and 1.12 electrons transfer from each Hf to H atom for *I4/mmm* and *Cmma* structure, at 100 and 200 GPa. For P_{2_1}/m , the number of electron transfer from each Hf is 1.29 and 0.42 at 250 GPa, which originates from its two different Hf site. In addition, the pressure dependence of δ (δ donates the values of charge transfer from Hf to H atom) for the above three phases is different. The δ depended on pressure in *Cmma* is smaller than that in *I4/mmm*. While turning to P_{2_1}/m , it exists two forms due to two inequitable Hf sites. The change of charge transfer may be related to the structural evolution. Overall, the ELF, the difference charge density and Bader analysis results reveal that the ionic bonds were formed between Hf and H, and HfH₂ was classified as a ionic cyrstal with the charge transferring from Hf to H atom.

We calculated the electron phonon coupling (EPC) parameter λ , the logarithmic average phonon frequency ω_{log} , and the electronic DOS at the Fermi level N(E_f) for *I4/mmm*, *Cmma* and *P*2₁/*m*. The *T_c* was estimated by using the Allen-Dynes modified McMillan equation²⁵ $T_c = \frac{\omega_{log}}{1.2} \exp\left[-\frac{1.04(1+\lambda)}{\lambda-\mu_*(1-0.62\lambda)}\right]$, For materials with $\lambda < 1$. 5, this equation has been found to be accurate. The Coulomb parameter set $\mu^* = 0.1-0.13$ are adopted for HfH₂. According to our calculations, the λ are 0.33, 0.64 and 0.87 for *I4/mmm* (at 1 atm), *Cmma* (at 180 GPa) and *P*2₁/*m* (at 260 GPa). The estimated T_c of *I4/mmm*, *Cmma* and *P*2₁/*m*, are 47–193 mK at 1 atm, 5.99–8.16 K at 180 GPa and 10.62–12.8 K at 260 GPa, respectively. We note that *I4/mmm* has a lower T_c value relative to the other two structures. For the *I4/mmm* (at 1 atm), the EPC parameter λ is 0.33, which indicate the electron-phonon interaction is fairly weak. In addition, the electronic DOS at the Fermi level N(E_f) for the phase *I4/mmm* is relatively small (3.978 states/spin/Ry/Unit cell). So the weak electron phonon coupling λ and small N(E_f) are the main factors, which lead to the low T_c . To study the pressure dependence of the superconducting critical temperature T_c of *I4/mmm*, *Cmma* and *P*2₁/*m*, the λ , ω_{log} and N(E_f) were calculated as summarized in Table 1. With the increasing pressure, the value of ω_{log} is increased in *I4/mmm*, while it is diminished in *Cmma* and

Structure	P(GPa)	$\omega_{ m log}({ m K})$	$N(\epsilon_f)$	λ	$T_{c}(\mathbf{K})\mu^{\star}=0.1$	$T_c(K)\mu^* = 0.13$
I4/mmm	1 atm	183.819	3.976	0.327	0.192	0.047
	10	201.203	3.486	0.294	0.081	0.012
	30	229.208	2.877	0.26	0.021	0.001
	50	253.173	2.497	0.242	0.008	0
Стта	180	292.708	6.195	0.643	8.159	5.988
	240	285.239	5.191	0.59	6.207	4.322
P2 ₁ /m	260	232.059	10.405	0.871	12.804	10.62
	280	218.68	8.322	0.787	7.962	9.911

Table 1. The calculated electron-phonon coupling parameters, electronic density of states at the Fermi level $N(E_f)$ (states/spin/Ry/Unit cell), the logarithmic average phonon frequency ω_{log} , and superconducting critical temperatures T_c of I4/mmm, Cmma and P2₁/m at different pressures.

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 $P2_1/m$. For N(E_f) and λ parameters, they both decrease as pressure increased, which mainly lead to the decrease of the T_c values for the above three structures.

Conclusion

In summary, we have extensively investigated structures and examined the structural stability of HfH_2 at high pressures up to 300 GPa through *ab initio* evolutionary simulations. Three structures *I4/mmm*, *Cmma* and $P2_1/m$ are predicted, and all of them are energetically much superior to others phases. The electronic structures are characterized as conductors with band overlap for *I4/mmm*, *Cmma* and $P2_1/m$ phases. The measured superconducting transition temperature T_c values for *I4/mmm*, *Cmma*, and $P2_1/m$ are 47–193 mK (at 1 atm), 5.99–8.16 K (at 180 GPa) and 10.62–12.8 K (260 GPa). Further analysis of the bonding nature shows that charges transfer from the hafnium to hydrogen with ionic bonds in HfH₂. The current study has great implications for researching other transition metal hydrides.

Methods

We have used the evolutionary algorithm USPEX code (Universal structure predictor: Evolutionary Xtallography)^{26–28} for crystal structure prediction to extensively explore the high-pressure phases of HfH_2 system at zero temperature. In the evolutionary structural predictions, the first generation of structures was always created randomly and its population size is 20-60 structures, increasing with system size. Every subsequent generation is produced from the best 60% of the previous generation. Moreover, the lowest-enthalpy structures always survived into the next generation. New structures are produced by variation operator heredity (60%), permutation (10%), and lattice mutation (30%). The energetic calculations and electronic structure calculations presented here are performed within density functional theory, carried out within the Vienna ab initio simulation package (VASP)²⁹. The generalized gradient approximation with Perdew-Burke-Ernzerh functinal³⁰ for the exchange correlation is employed. The projector-augmented wave (PAW)³¹ method is adopted with valence electrons of $5d^26s^2$ and $1s^1$ and cutoff radii of 2.5 and 0.8 a.u. for Hf and H atoms, respectively. The electronic wave functions were expanded in a plane-wave basis set with a cutoff energy of 800 eV and appropriate Monkhorst-Pack meshes were chosen for all structures to ensure that enthalpy calculations are well converged to better than 1 meV/ atom. In the geometrical optimization, all forces on atoms were converged to less than 0.005 eV/Å. We used the Bader charge analysis³²⁻³⁴ to calculate the electronic charge transfer. To determine the dynamical stability of the studied structures, the phonon calculations are carried out using a supercell approach³⁵ with the PHONOPY code³⁶. Electron-phonon coupling (EPC) calculations were carried out using the linear response theory through the Quantum ESPRESSO package³⁷. The kinetic energy cutoff was set 90 Ry. And the q-point mesh of the electron-phonon interaction matrix element adopted $4 \times 4 \times 4$, $4 \times 4 \times 3$ and $2 \times 3 \times 3$ for I4/mmm, Cmma and P2₁/m, respectively.

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Author Contributions

T.C. initiated the project. Y.L. performed the first principle calculations and prepared all figures. Y.L., X.H., D.D. and T.C. analyzed the data and wrote the manuscript text. F.T., H.L., D.L., Z.Z., X.S., H.Y., H.Z. and B.L. reviewed the manuscript.

Additional Information

Supplementary information accompanies this paper at http://www.nature.com/srep

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